TOSHIBA Transistor Silicon NPN Epitaxial Type (Darlington Power Transistor)

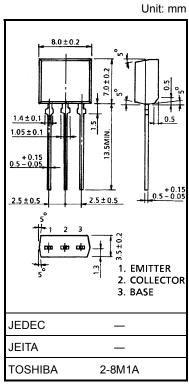
2SD2480

Micro Motor Drive, Hammer Drive Applications Switching Applications Power Amplifier Applications

- High DC current gain: $h_{FE} = 2000$ (min) ($V_{CE} = 2$ V, $I_{C} = 1$ A)
- Low saturation voltage: VCE (sat) = 1.5 V (max) (IC = 1 A, IB = 1 mA)

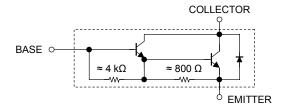
Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V_{CBO}	100	V	
Collector-emitter voltage		V _{CEO}	100	V	
Emitter-base voltage		V _{EBO}	8	٧	
Collector current	DC	Ic	2	А	
	Pulse	I _{CP}	3		
Base current		Ι _Β	0.5	Α	
Collector power dissipation		Pc	1.3	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



Weight: 0.55 g (typ.)

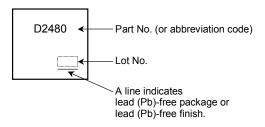
Equivalent Circuit



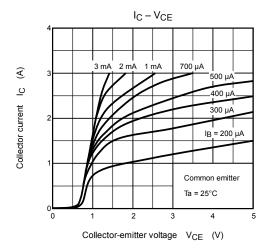
Electrical Characteristics (Ta = 25°C)

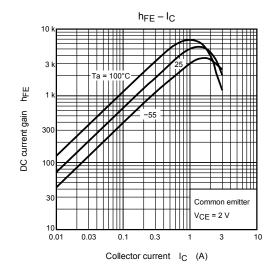
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I _{CBO}	V _{CB} = 80 V, I _E = 0	_	_	10	μΑ
Emitter cut-off current		I _{EBO}	V _{EB} = 8 V, I _C = 0	_	_	4	mA
Collector- emitter breakdown voltage		V (BR) CEO	I _C = 10 mA, I _B = 0	100	_	_	V
DC current gain		h _{FE}	V _{CE} = 2 V, I _C = 1 A (pulse)	2000	_	_	
Collector-emitter saturation voltage		V _{CE (sat)}	I _C = 1 A, I _B = 1 mA (pulse)	_	_	1.5	V
Base-emitter saturation voltage		V _{BE (sat)}	I _C = 1 A, I _B = 1 mA (pulse)	_	_	2.0	V
Transition frequency		f _T	V _{CE} = 2 V, I _C = 0.5 A	_	100	_	MHz
Collector output capacitance		C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz	_	20	_	pF
Switching time	Turn-on time	t _{on}	$20 \mu s$ Input B_1 Output C_1 C_2 C_3 C_4 C_5 C_6 C_6 C_7 C_8	_	0.4	_	
	Storage time	t _{stg}		_	4.0	_	μs
	Fall time	t _f		_	0.6	_	

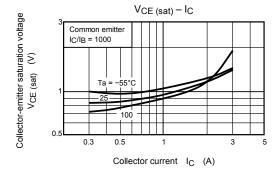
Marking

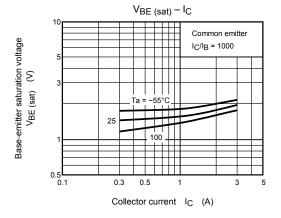


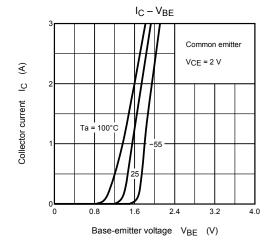
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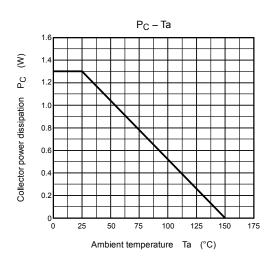


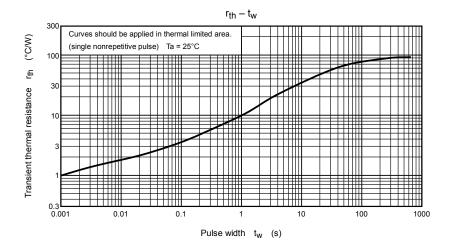


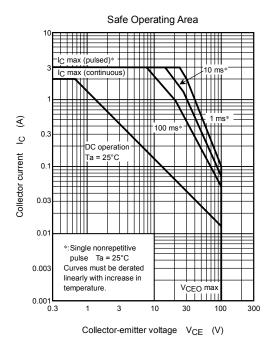












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